

Russian Samples

- Mamaev reported “World Record” 91.5% polarization and 0.85% QE @830 nm in December 20006. (Wafer 7-307)
- Same structure was grown on a Bragg reflector in hopes of achieving world highest polarization and QE. (Wafer 7-308)
- Mamaev sent us two test samples,
 - 7-307 1 cm x 1 cm
 - 7-308 $\frac{1}{4}$ of 3” wafer
- X-rayed un-used samples
- QE/polarization measurements

Structures

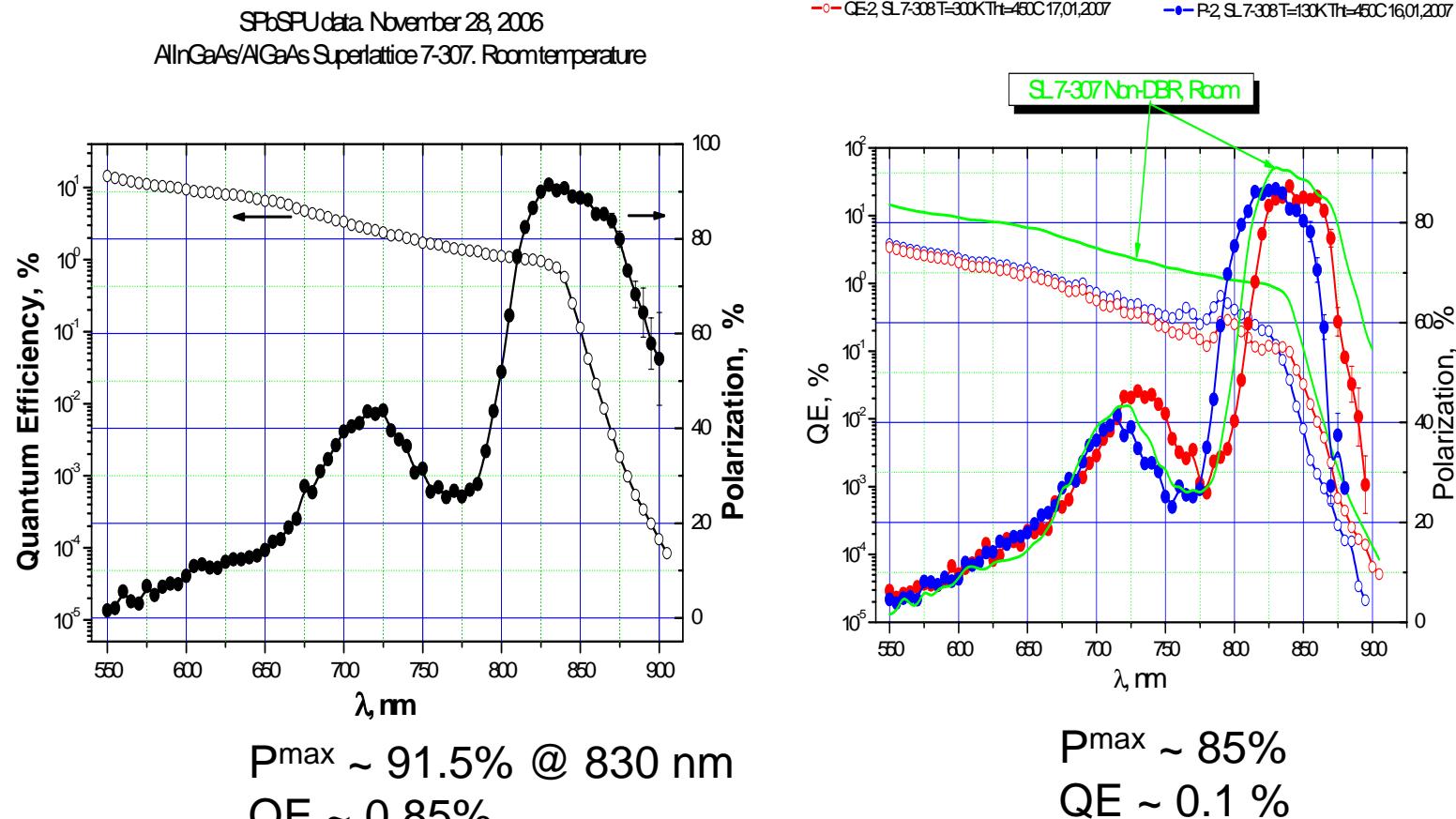
- 7-307

- GaAs cap 6 nm Be: 7×10^{18}
- $\text{Al}_{0.39}\text{Ga}_{0.61}\text{As}$ 2.1 nm
- $\text{In}_{0.2}\text{Al}_{0.2}\text{Ga}_{0.6}\text{As}$ 5.4 nm
 - Repeat x12 Be: 3×10^{17}
- $\text{Al}_{0.35}\text{Ga}_{0.65}\text{As}$ 0.3 um
- GaAs buffer 0.2 um
- GaAs s.i. substrate

- 7-308

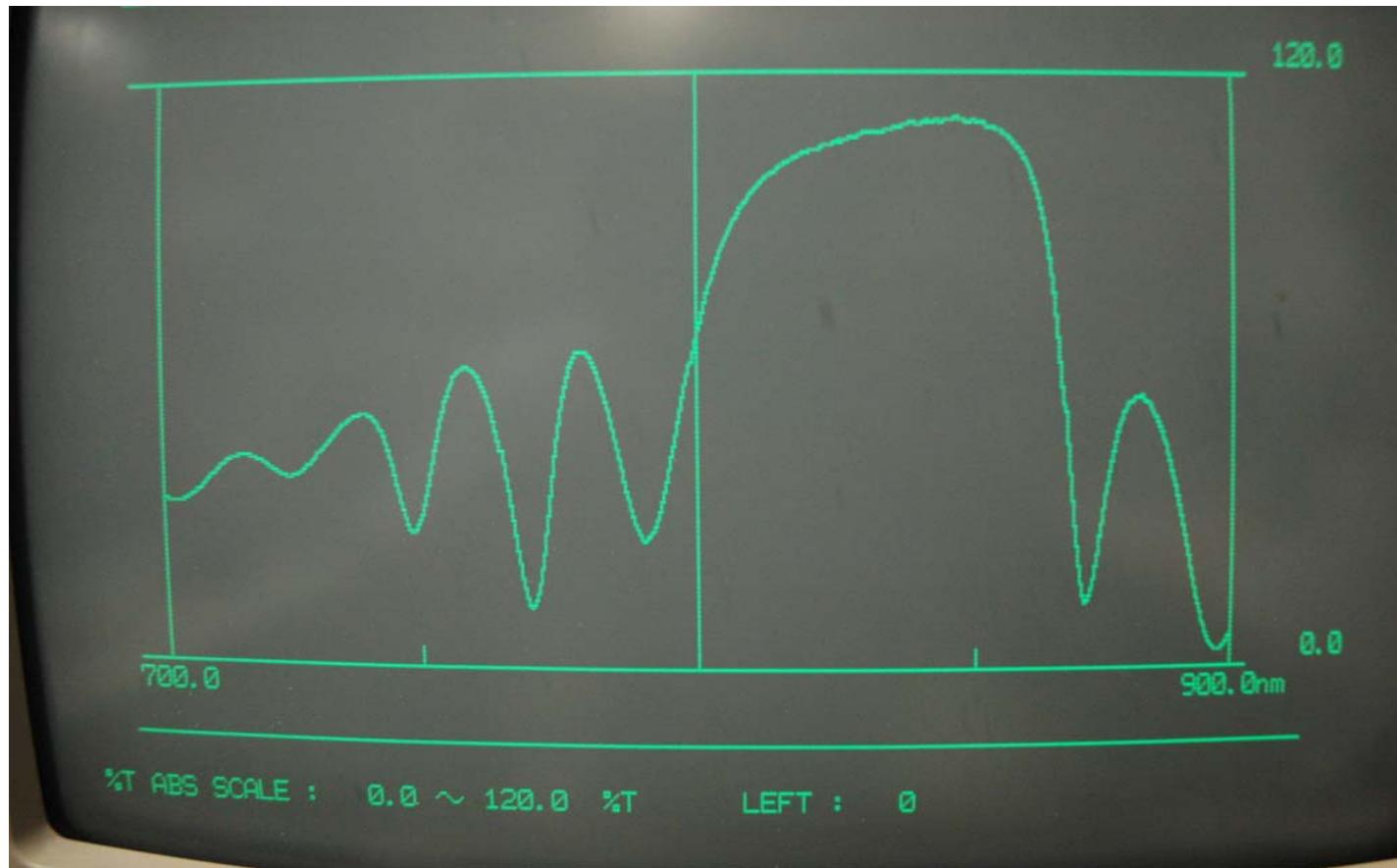
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- $\text{Al}_{0.39}\text{Ga}_{0.61}\text{As}$ 2.1 nm
- $\text{In}_{0.2}\text{Al}_{0.2}\text{Ga}_{0.6}\text{As}$ 5.4 nm
 - Repeat x12 Be: 3×10^{17}
- $\text{Al}_{0.35}\text{Ga}_{0.65}\text{As}$ 0.3 um
- GaAs buffer 12 nm
- GaAs buffer 20 nm
- DBR (AlGaAs/GaAs superlattice)
- GaAs substrate

Two samples from St. Petersburg



As cap enabled heat-cleaning at 450° C.

Reflectivity of 7-308

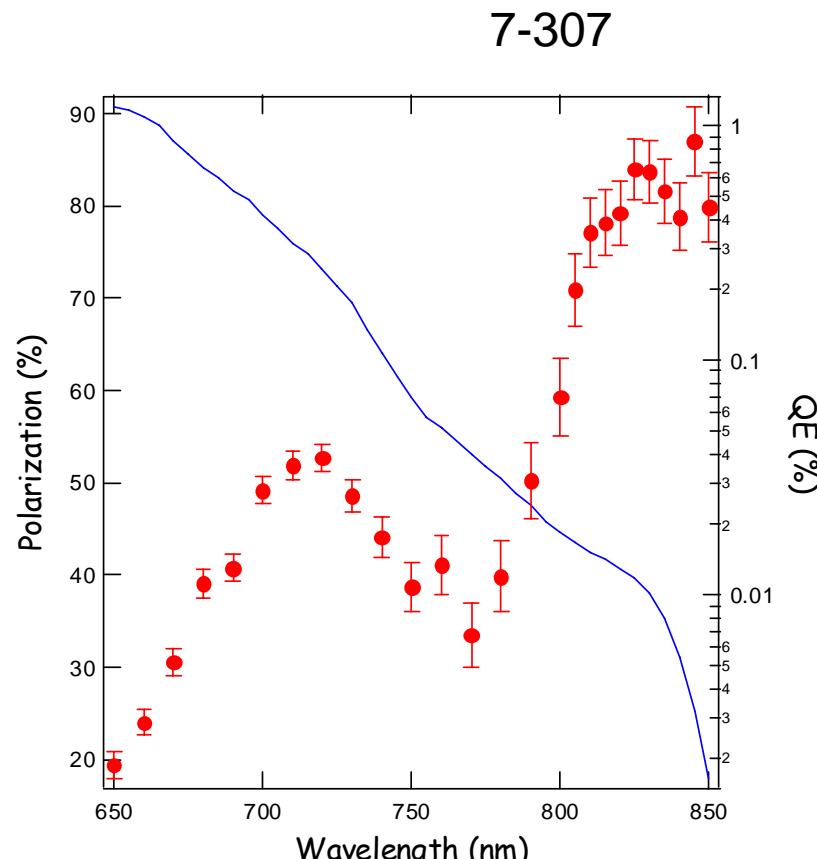


DBR looks OK.

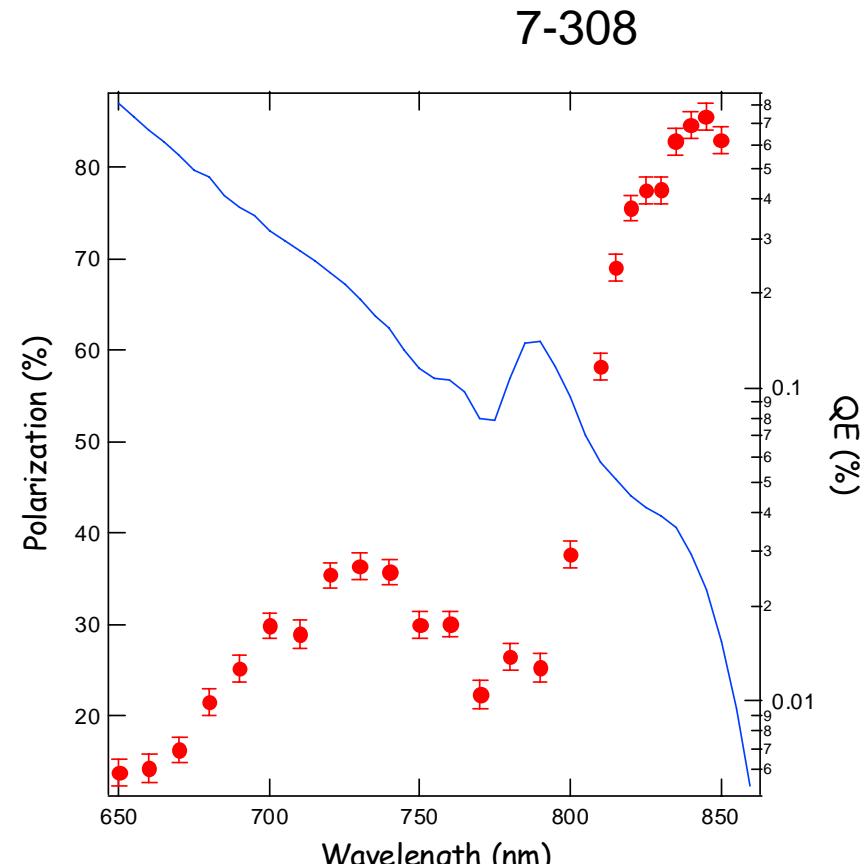
CTS measurements

- 7-308
 - Sample #1
 - Assuming an As cap, no chemical cleaning was made.
 - After three heat-cleanings at 500° C, 520° C, and 540° C, QE was never high enough to measure QE/Polarization.
 - Sample #2
 - Standard TCE cleaning + NH₄OH stripping
 - 525° C heat-cleaning
- 7-307
 - Standard TCE cleaning + NH₄OH stripping
 - 525° C heat-cleaning

CTS measurements

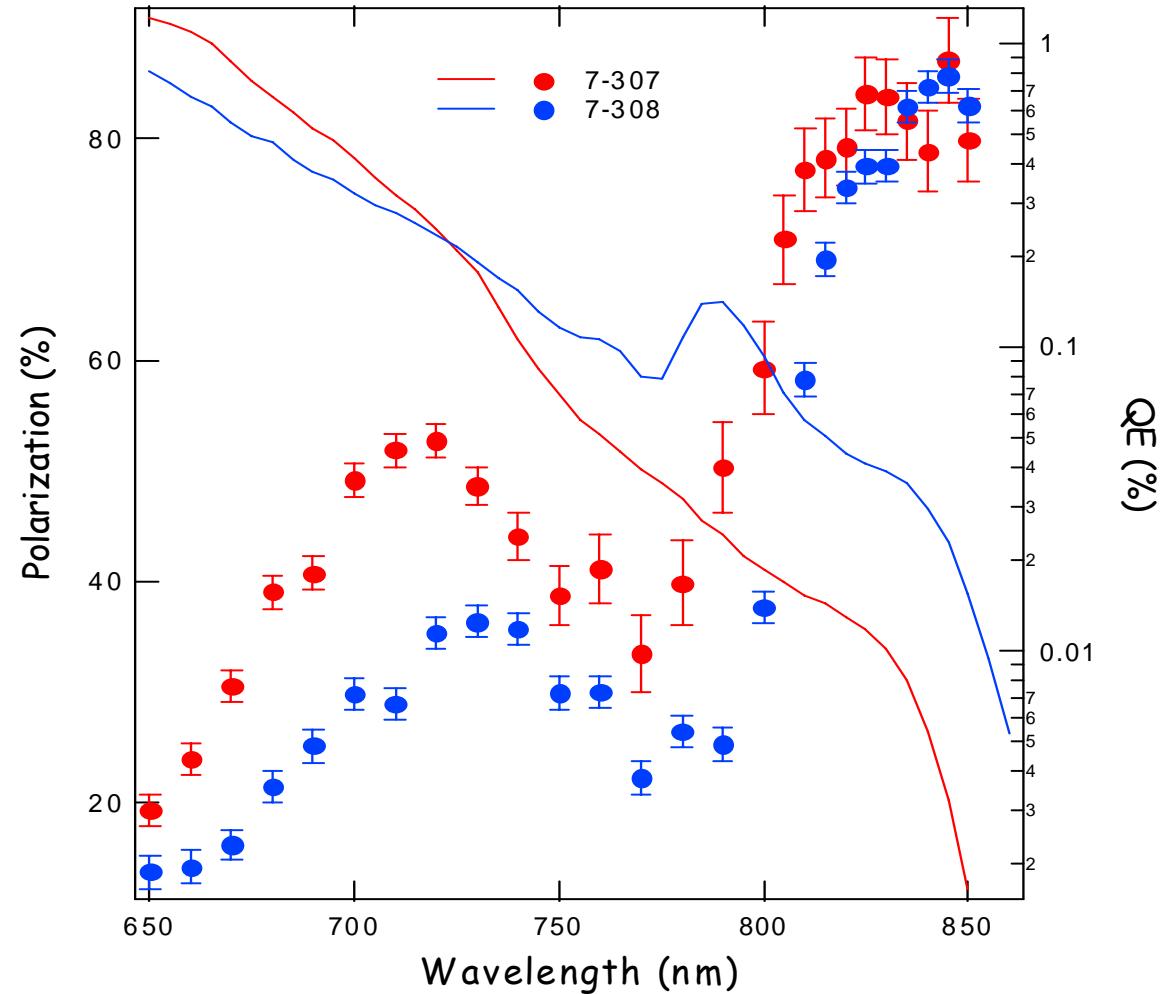


Peak polarization ~85%
QE ~0.015%



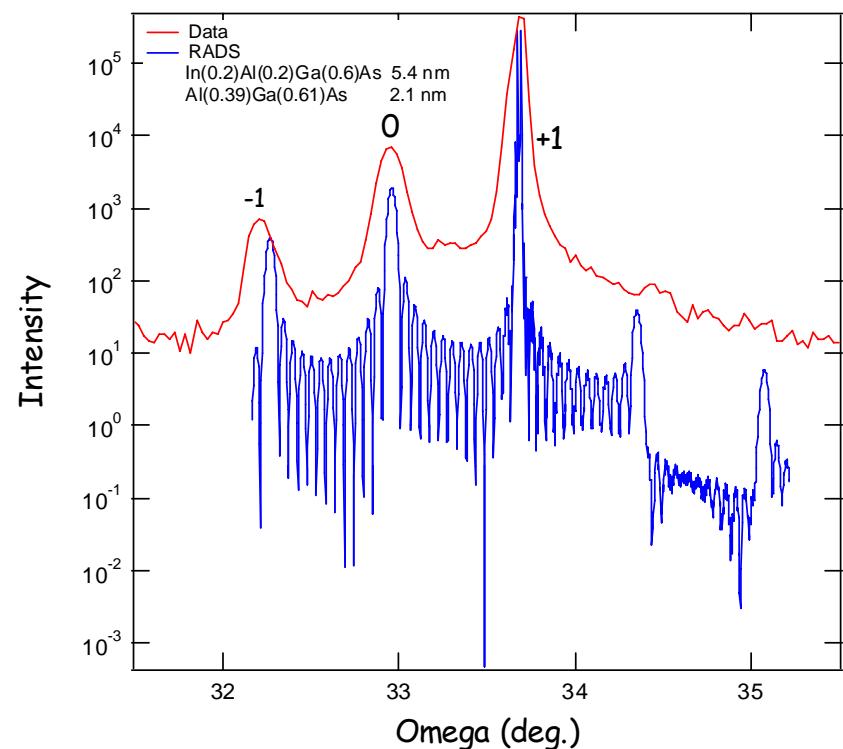
Peak polarization ~85%
QE ~0.025%

Comparison



X-ray

7-307



7-308

